



**THE DATASHEET OF  
FZT792ATA**



## Features

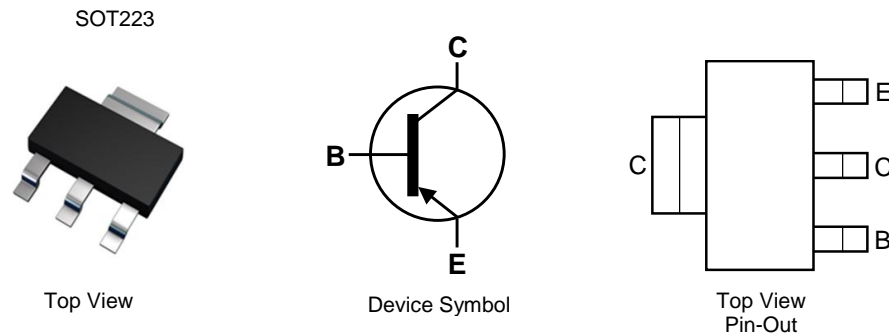
- $BV_{CEO} > -70V$
- $I_C$  Max. -2A High Continuous Current
- Low Saturation Voltage  $V_{CE(sat)} < -500mV @ -1A$
- Complementary NPN Type: FZT692B
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please [contact us](mailto:contact@diodes.com) or your local Diodes representative. <https://www.diodes.com/quality/product-definitions/>**

## Mechanical Data

- Package: SOT223 (Type DN)
- Package Material: Molded Plastic. "Green" Molding Compound; UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208
- Weight: 0.112 grams (Approximate)

## Applications

- Battery-powered circuits

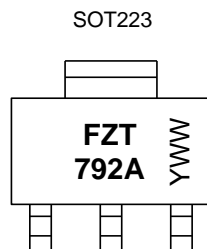


## Ordering Information (Note 4)

Orderable Part Number	Marking	Reel Size (inches)	Tape Width (mm)	Packing	
				Quantity	Carrier
FZT792ATA	FZT792A	7	12	1,000	Reel

- Notes:
1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied..
  2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
  4. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

## Marking Information



FZT 792A = Product Type Marking Code  
 YWW = Date Code Marking  
 Y or  $\bar{Y}$  = Last Digit of Year (ex: 2 = 2022)  
 WW or  $\bar{W}W$  = Week Code (01-53)

**Absolute Maximum Ratings** (@  $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	$V_{CBO}$	-75	V
Collector-Emitter Voltage	$V_{CEO}$	-70	V
Emitter-Base Voltage	$V_{EBO}$	-7	V
Continuous Collector Current	$I_C$	-2	A
Peak Pulse Current	$I_{CM}$	-5	A

**Thermal Characteristics** (@  $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

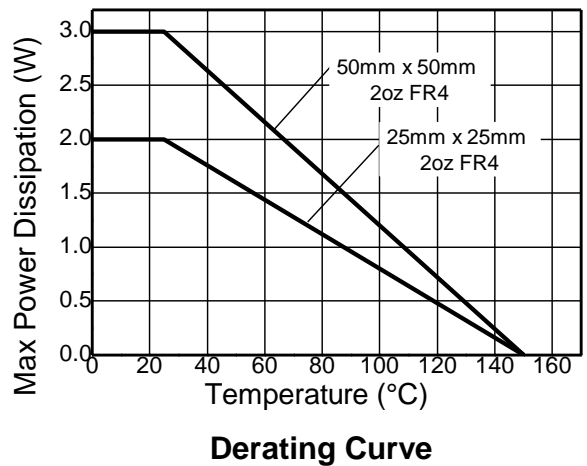
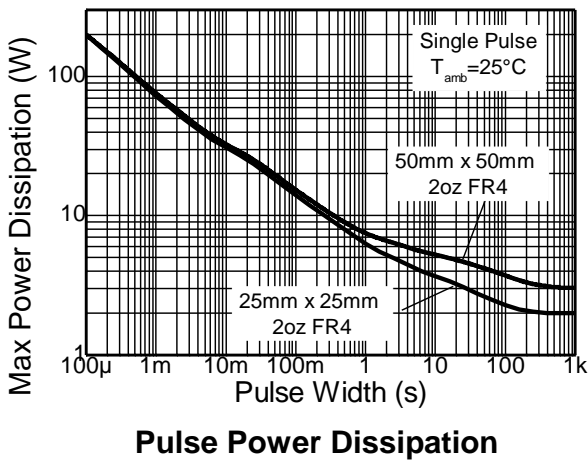
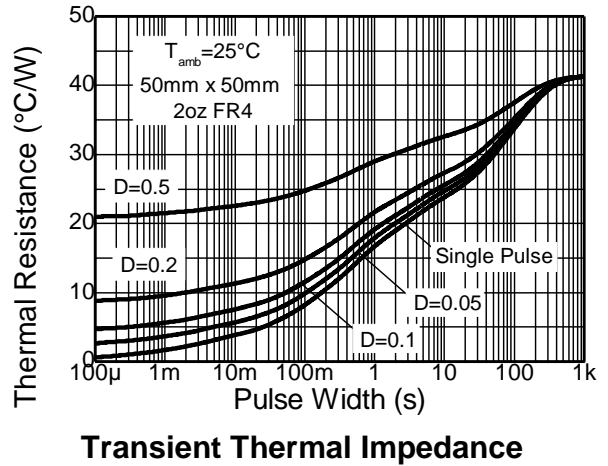
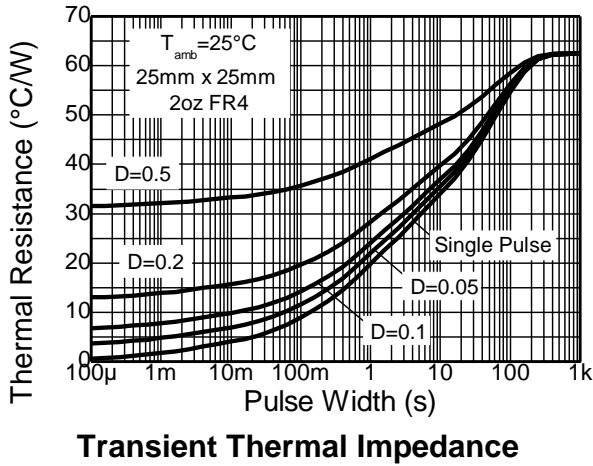
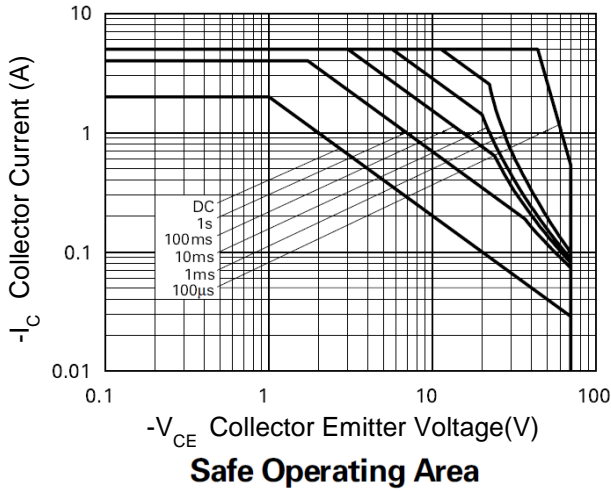
Characteristic	Symbol	Value	Unit
Power Dissipation	$P_D$	(Note 5)	3.0
		(Note 6)	2.0
		(Note 7)	1.6
		(Note 8)	1.2
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	(Note 5)	41.7
		(Note 6)	62.5
		(Note 7)	78.1
		(Note 8)	104
Thermal Resistance Junction to Lead	$R_{\theta JL}$	12.9	
Operating and Storage Temperature Range	$T_J, T_{STG}$	-55 to +150	$^\circ\text{C}$

**ESD Ratings** (Note 10)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	C

- Notes:
- For a device mounted with the collector lead on 50mm x 50mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
  - Same as Note 5, except the device is mounted on 25mm x 25mm 2oz copper.
  - Same as Note 5, except the device is mounted on 25mm x 25mm 1oz copper.
  - Same as Note 5, except the device is mounted on minimum recommended pad layout.
  - Thermal resistance from junction to solder-point (at the end of the collector lead).
  - Refer to JEDEC specification JESD22-A114 and JESD22-A115.

**Thermal Characteristics and Derating Information**

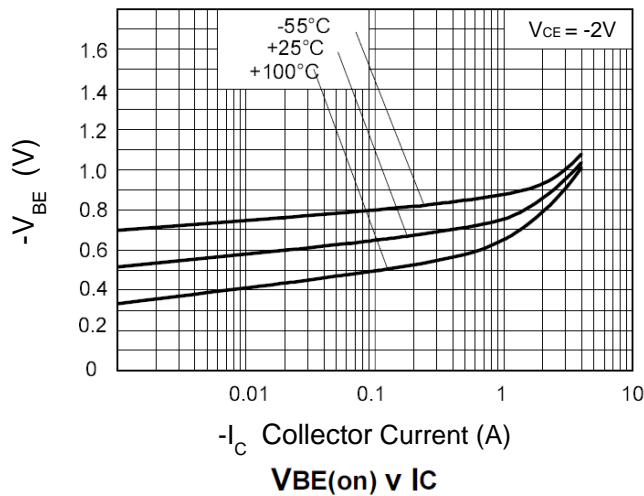
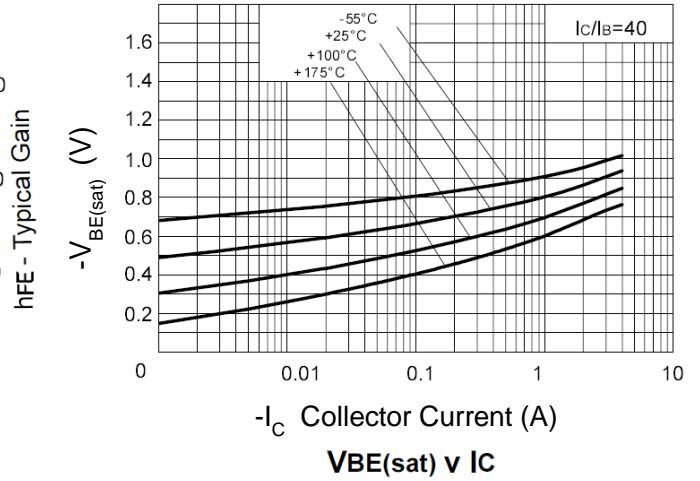
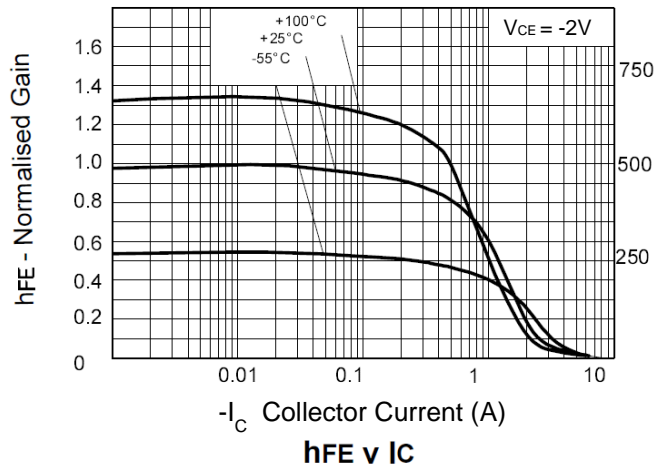
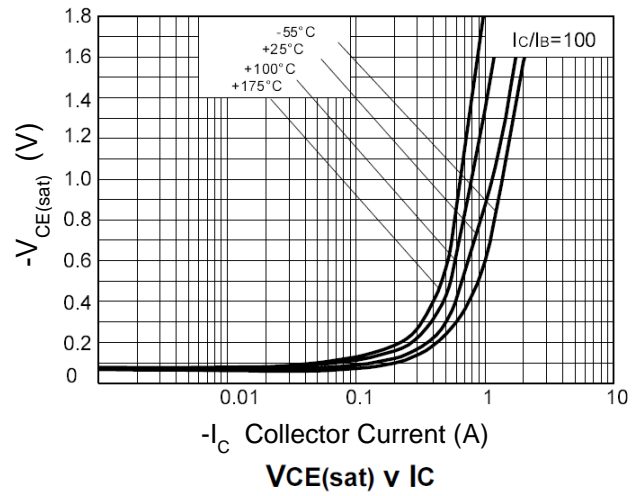
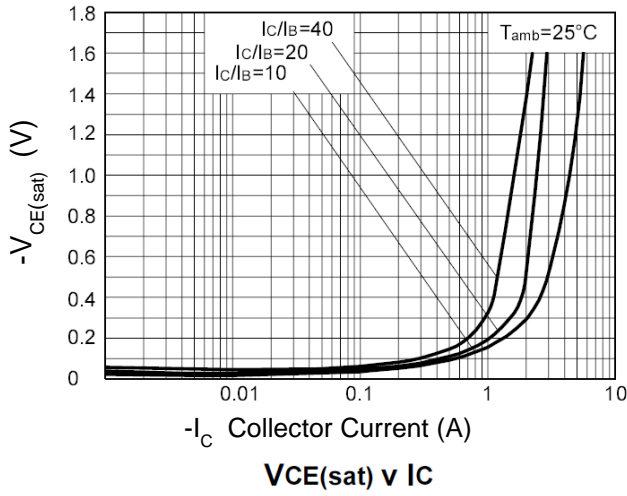


**Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	-75	-100	-	V	I <sub>C</sub> = -100μA
Collector-Emitter Breakdown Voltage (Note 11)	BV <sub>CEO</sub>	-70	-90	-	V	I <sub>C</sub> = -10mA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-7	-8.5	-	V	I <sub>E</sub> = -100μA
Collector Cut-Off Current	I <sub>CBO</sub>	-	1	-100	nA	V <sub>CB</sub> = -40V
		-	-	-10	μA	V <sub>CB</sub> = -40V, T <sub>amb</sub> = +100°C
Emitter Cut-Off Current	I <sub>EBO</sub>	-	1	-100	nA	V <sub>EB</sub> = -4V
Collector-Emitter Saturation Voltage (Note 11)	V <sub>CE(sat)</sub>	-	-0.30	-0.45	V	I <sub>C</sub> = -500mA, I <sub>B</sub> = -5mA
		-	-0.30	-0.50		I <sub>C</sub> = -1A, I <sub>B</sub> = -25mA
		-	-0.30	-0.50		I <sub>C</sub> = -2A, I <sub>B</sub> = -200mA
Base-Emitter Saturation Voltage (Note 11)	V <sub>BE(sat)</sub>	-	-0.80	-0.95	V	I <sub>C</sub> = -1A, I <sub>B</sub> = -25mA
Base-Emitter Turn-On Voltage (Note 11)	V <sub>BE(on)</sub>	-	-0.75	-	V	I <sub>C</sub> = -1A, V <sub>CE</sub> = -2V
DC Current Gain (Note 11)	h <sub>FE</sub>	300	-	800	-	I <sub>C</sub> = -10mA, V <sub>CE</sub> = -2V
		250	-	-		I <sub>C</sub> = -500mA, V <sub>CE</sub> = -2V
		200	-	-		I <sub>C</sub> = -1A, V <sub>CE</sub> = -2V
Current Gain-Bandwidth Product	f <sub>T</sub>	100	160	-	MHz	V <sub>CE</sub> = -5V, I <sub>C</sub> = -50mA f = 50MHz
Turn-On Time	t <sub>on</sub>	-	35	-	ns	V <sub>CC</sub> = -10V, I <sub>C</sub> = -500mA
Turn-Off Time	t <sub>off</sub>	-	750	-	ns	I <sub>B1</sub> = -I <sub>B2</sub> = -50mA
Input Capacitance	C <sub>ibo</sub>	-	225	-	pF	V <sub>EB</sub> = -0.5V, f = 1MHz
Output Capacitance	C <sub>obo</sub>	-	25	-	pF	V <sub>CB</sub> = -10V, f = 1MHz

Note: 11. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%.

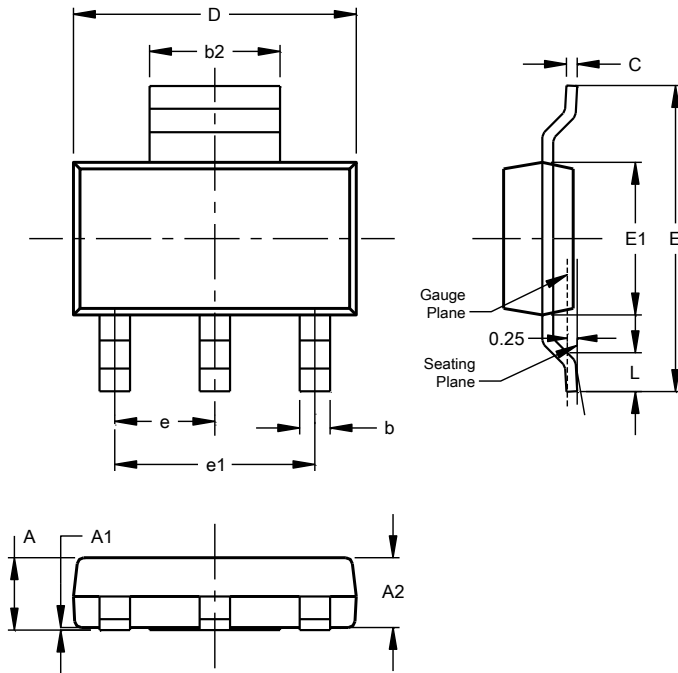
**Typical Electrical Characteristics** (@  $T_A = +25^\circ\text{C}$ , unless otherwise specified.)



## Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

SOT223 (Type DN)

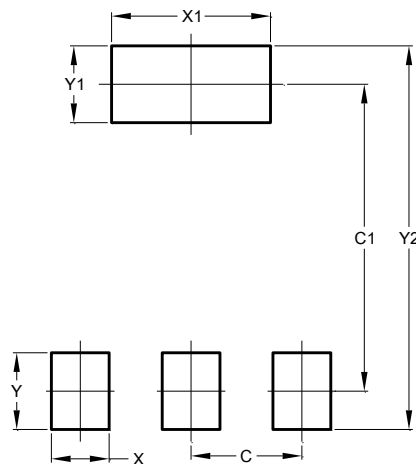


SOT223 (Type DN)			
Dim	Min	Max	Typ
A	--	1.70	--
A1	0.01	0.15	--
A2	1.50	1.68	1.60
b	0.60	0.80	0.70
b2	2.90	3.10	--
c	0.20	0.32	--
D	6.30	6.70	--
E	6.70	7.30	--
E1	3.30	3.70	--
e	--	--	2.30
e1	--	--	4.60
L	0.85	--	--
All Dimensions in mm			

## Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

SOT223 (Type DN)



Dimensions	Value (in mm)
C	2.30
C1	6.40
X	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00

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